NSN 5961-01-186-3896



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-186-3896 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** Between 1.500 inches and 1.800 inches **Overall Diameter:** 0.230 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-18 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case and mounting pad **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 200.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 360.0 milliwatts small-signal input power, common-collector **Transfer Ratio:** 100.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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